### MMVL105GT1

Preferred Device

## **Silicon Tuning Diode**

This device is designed in the Surface Mount package for general frequency control and tuning applications. It provides solid–state reliability in replacement of mechanical tuning methods.

- Controlled and Uniform Tuning Ratio
- Device Marking: 4E



#### ON Semiconductor

Formerly a Division of Motorola

http://onsemi.com

# 30 VOLT VOLTAGE VARIABLE CAPACITANCE DIODE

#### **MAXIMUM RATINGS**

Symbol	mbol Rating		Unit
V <sub>R</sub>	Continuous Reverse Voltage	30	Vdc
I <sub>F</sub>	Peak Forward Current	200	mAdc

#### THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
P <sub>D</sub>	Total Device Dissipation FR–5 Board,*  T <sub>A</sub> = 25°C  Derate above 25°C	200 1.57	mW mW/°C
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	635	°C/W
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature	150	°C

<sup>\*</sup>FR-4 Minimum Pad



PLASTIC SOD-323 CASE 477



#### ORDERING INFORMATION

Device	Package	Shipping		
MMVL105GT1	SOD-323	3000 / Tape & Reel		

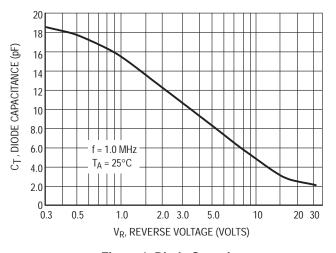
**Preferred** devices are recommended choices for future use and best overall value.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μAdc)		V <sub>(BR)R</sub>	30	_	Vdc
Reverse Voltage Leakage Current (V <sub>R</sub> = 28 Vdc)		I <sub>R</sub>	_	50	nAdc

Device Type	C <sub>T</sub> V <sub>R</sub> = 25 Vdc, f = 1.0 MHz pF		Q V <sub>R</sub> = 3.0 Vdc f = 50 MHz	C <sub>R</sub> C <sub>3</sub> /C <sub>25</sub> f = 1.0 MHz	
	Min	Max	Тур	Min	Max
MMVL105GT1	1.5	2.8	250	4.0	6.5

#### TYPICAL CHARACTERISTICS



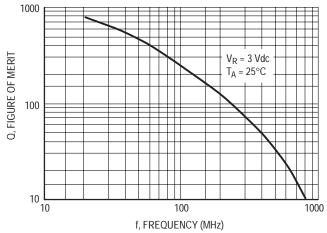


Figure 1. Diode Capacitance

Figure 2. Figure of Merit

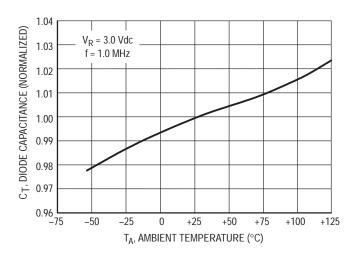
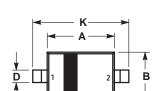


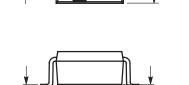
Figure 3. Diode Capacitance

#### MMVL105GT1

#### **PACKAGE DIMENSIONS**



SOD-323 PLASTIC PACKAGE CASE 477-02 ISSUE A



NOTE 3



- NOTES:

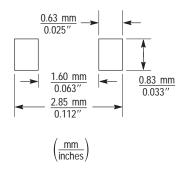
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. LEAD THICKNESS SPECIFIED PER LIF DRAWING WITH SOLDER PLATING.

	MILLIN	IETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	1.60	1.80	0.063	0.071		
В	1.15	1.35	0.045	0.053		
С	0.80	1.00	0.031	0.039		
D	0.25	0.40	0.010	0.016		
Е	0.15 REF		0.006 REF			
Н	0.00	0.10	0.000	0.004		
J	0.089	0.177	0.0035	0.0070		
K	2.30	2.70	0.091	0.106		

STYLE 1: PIN 1. CATHODE 2. ANODE



SOD-323 Soldering Footprint

#### MMVL105GT1

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